

↑ E<sub>u</sub>

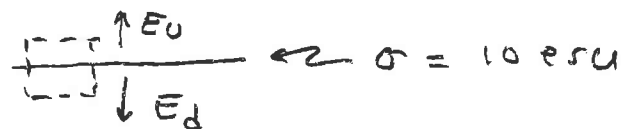
$$E_u = (\sigma_{B_t} + \Delta\sigma) 4\pi$$

↓ E<sub>d</sub>

$$E_d = (\sigma_{\sigma_{B_b}} - \Delta\sigma) 4\pi$$

How do we determine  $\Delta\sigma$ ?

Expect at a distance, system should look like



with  $E_u = E_d$   $\rightarrow E_u + E_d = 4\pi \cdot 10 \text{ esu}$

$$\therefore \sigma_{B_t} + \Delta\sigma = 5 \text{ esu} \quad E_u = E_d = \frac{10 \text{ esu}}{2\pi}$$

$$\sigma_{B_b} - \Delta\sigma = 5 \text{ esu}$$

$$\frac{5}{13} \times 10 + \Delta\sigma = 5 \text{ esu} \Rightarrow \Delta\sigma = \left(\frac{1}{2} - \frac{5}{13}\right) \times 10$$

$$\frac{8}{13} \times 10 - \Delta\sigma = 5 \text{ esu} \Rightarrow \Delta\sigma = \left(\frac{8}{13} - \frac{1}{2}\right) \times 10$$

If  $E_u \neq E_d$  then  $E_u = \frac{5 \text{ esu}}{4\pi} + \Delta E$

$$E_d = \frac{5 \text{ esu}}{4\pi} - \Delta E$$

and we have applied extra uniform  $\vec{E} = \Delta E \hat{z}$  not specified in problem.

# E Capacitance 01/25/2022

1. Given  $N$  conductors  $C_i$   $1 \leq i \leq N$  each carrying charge  $Q_i$  and at the potential  $\phi_i$ , how are the  $Q_i$  and  $\phi_i$  related?

(choose  $\lim_{r \rightarrow \infty} \phi(r) = 0$ )



Solve  $N$  different problems:

$k^{\text{th}}$  problem has solution  $\phi^{(k)}(\vec{r})$

obeying: ①  $\nabla^2 \phi^{(k)}(r) = 0$  outside conductor

② on the  $i^{\text{th}}$  conductor  $\phi^{(k)}(r) = \delta_{ik} \phi_k$

③  $\lim_{|\vec{r}| \rightarrow \infty} \phi^{(k)}(\vec{r}) = 0$

## E Capacitance

(16)

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If  $Q_i^{(k)}$  is the charge on the  $i^{\text{th}}$  conductor for the  $k^{\text{th}}$  problem,

(17)

$$Q_i^{(k)} = \frac{1}{4\pi} \int_{\partial C_i} \vec{E}^{(k)}(\vec{r}) \cdot \hat{n} dS$$

$$= \frac{1}{4\pi} \int_{\partial C_i} \vec{\nabla} \Phi^{(k)}(\vec{r}) \cdot \hat{n} dS \times \Phi_k$$

$$= \underbrace{\hspace{10em}}_{\Phi_k} \times \Phi_k$$

must not depend on  $\Phi_k \rightarrow C_{ik}^{(k)}$

Solve our general problem by superimposing these  $N$  problems

$$\Phi(\vec{r}) = \sum_{k=1}^N \Phi^{(k)}(\vec{r})$$

$$\Phi(\vec{r}) \Big|_{\vec{r} \in C_i} = \sum_k \Phi^{(k)}(\vec{r}) \Big|_{\vec{r} \in C_i} = \Phi_i$$

$$Q_i = \sum_{k=1}^N Q_i^{(k)} = \sum_k C_{ik} \Phi_k$$

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(17)

Thus if we can compute the  $N^2$  coefficients of capacitances  $C_{ik}$  the charges  $Q_i$  are linearly related to the potentials  $\phi_k$

$$Q_i = \sum_{k=1}^N C_{ik} \phi_k$$

2. Find the capacitance of a conducting sphere of radius  $R$ :

$$Q_1 = C_{11} \phi_1$$



$$\phi(\vec{r}) = \begin{cases} \frac{Q}{r} & r \geq R \\ \frac{Q}{R} & r \leq R \end{cases}$$

For a hollow sphere,

$$Q_1 = \frac{Q_1}{R} \text{ or } C_{11} = R$$

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3. Consider two conductors



for  $C_{ij}$

$$\begin{pmatrix} \phi_1 \\ \phi_2 \end{pmatrix} = \begin{pmatrix} C_{11} & C_{12} \\ C_{21} & C_{22} \end{pmatrix} \begin{pmatrix} Q_1 \\ Q_2 \end{pmatrix}$$

Consider further the case of practical interest where the system of two conductors is neutral with

$Q_1 = -Q_2 = Q$ , then

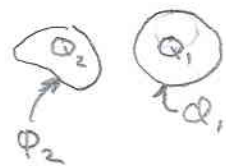
$$\begin{aligned} \begin{pmatrix} \phi_1 \\ \phi_2 \end{pmatrix} &= C^{-1} \begin{pmatrix} Q \\ -Q \end{pmatrix} = \frac{1}{C_{11}C_{22} - C_{21}C_{12}} \begin{pmatrix} C_{22} & -C_{12} \\ -C_{21} & C_{11} \end{pmatrix} \begin{pmatrix} Q \\ -Q \end{pmatrix} \\ &= \frac{1}{C_{11}C_{22} - C_{21}C_{12}} \begin{pmatrix} [C_{22} + C_{12}] Q \\ -[C_{21} + C_{11}] Q \end{pmatrix} \end{aligned}$$

If we use  $\phi = \phi_1 - \phi_2$  as the potential difference between the two conductors

$$\phi = \frac{C_{22} + C_{12} + C_{21} + C_{11}}{C_{22}C_{11} - C_{12}C_{21}} Q \equiv \frac{Q}{C}$$

where  $C$  is the usual capacitance

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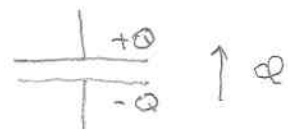
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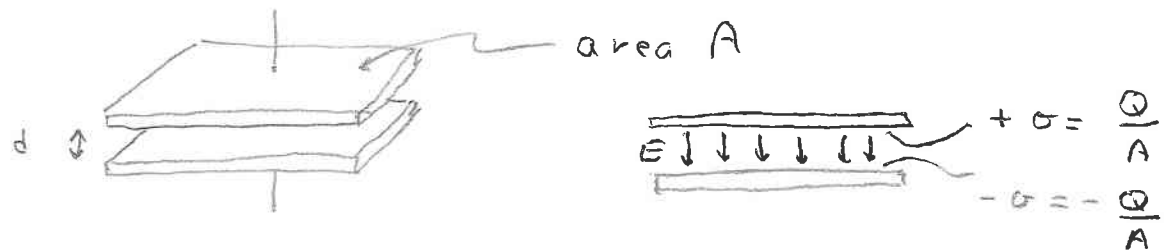
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This is a detailed description of a capacitor



4 Examine a parallel plate capacitor



$$E = 4\pi\sigma = \frac{4\pi Q}{A} \quad \phi = Ed = \frac{4\pi d}{A} Q = \frac{Q}{C}$$

$$C = \frac{A}{4\pi d}$$

The larger  $A$  and the smaller  $d$  the larger is the charge  $Q$  that can be stored for fixed voltage  $\phi$

5 Units:

$$\frac{esu}{V} \quad C = \frac{Q}{V} \sim \text{cm}$$

$$SI \quad C = \frac{Q}{V} \sim \frac{\text{Coulomb}}{\text{Volt}} = \text{Farad}$$

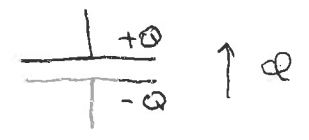
$$1 \text{ Farad} = \frac{1 \text{ Coulomb}}{1 \text{ Volt}} = \frac{3 \times 10^9 \text{ esu}}{1/300 \text{ statvolt}} = 9 \times 10^{11} \text{ cm}$$

↑  
(2.99792458)<sup>2</sup>

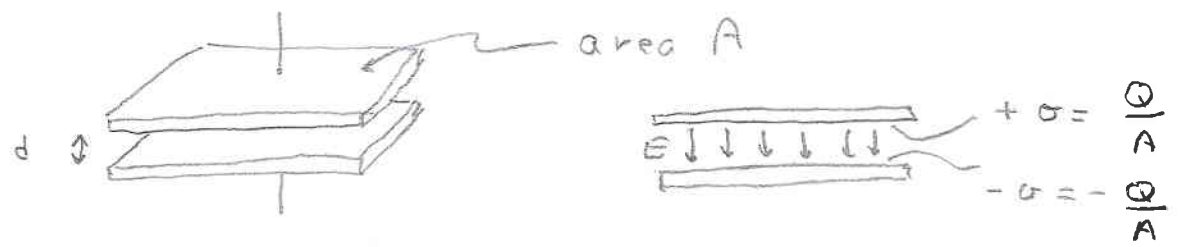
A Farad is large

A cm is small

This is a detailed description of a capacitor



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$$E = 4\pi\sigma = \frac{4\pi Q}{A} \quad Q = Ed = \frac{4\pi d}{A} Q = \frac{Q}{C}$$

$C = \frac{A}{4\pi d}$  The larger A and the smaller d the larger is the charge Q that can be stored for fixed voltage Q

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A Farad is large  
A cm is small

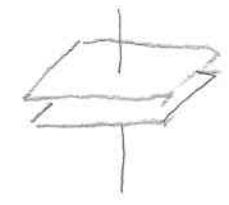
6. Energy stored in a capacitor

$$V \uparrow \frac{+Q}{-Q} \xrightarrow{\delta Q} \frac{+Q+\delta Q}{-(Q+\delta Q)}$$

$$\delta E = V \delta Q = \frac{Q}{C} \delta Q$$

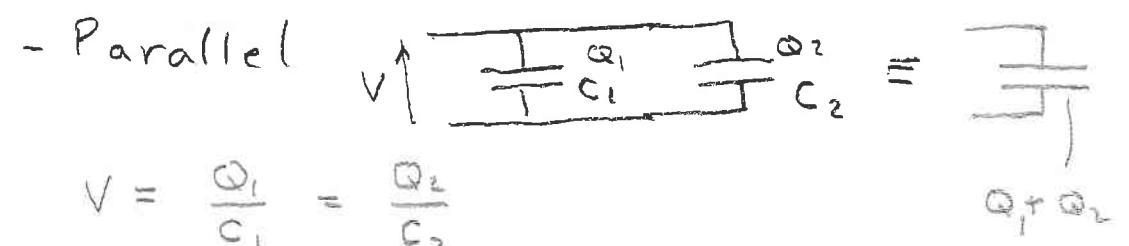
$$E = \int_0^Q dE' = \int_0^Q \frac{Q}{C} dQ = \frac{Q^2}{2C}$$

Try out our energy density result



$$\text{Energy} = \frac{E^2}{8\pi} Ad = \frac{(4\pi\sigma)^2 Ad}{8\pi} = \frac{1}{2} \frac{4\pi d}{A} Q^2 = \frac{1}{2} \frac{Q^2}{C} V$$

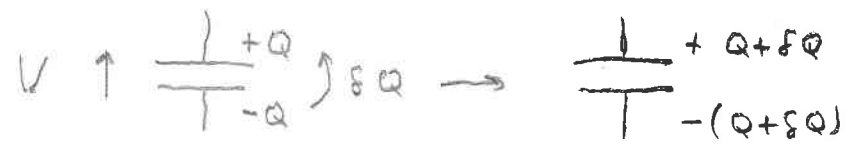
7. Combine capacitors



$$V = \frac{Q_1}{C_1} = \frac{Q_2}{C_2}$$

$$C = \frac{Q_1 + Q_2}{V} = C_1 + C_2$$

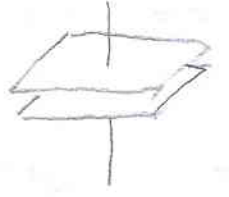
### 6. Energy stored in a capacitor



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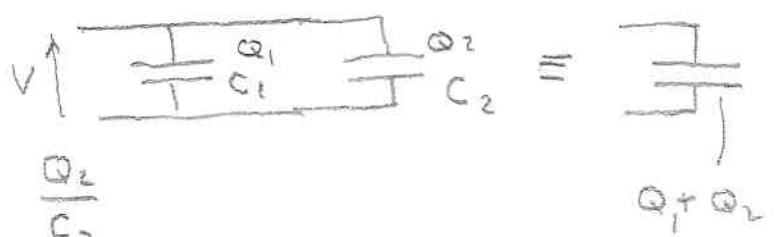
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$$\begin{aligned} \text{Energy} &= \frac{E^2}{8\pi} Ad = \frac{(4\pi\sigma)^2 Ad}{8\pi} \\ &= \frac{1}{2} \frac{4\pi d}{A} Q^2 = \frac{1}{2} \frac{Q^2}{C} \checkmark \end{aligned}$$

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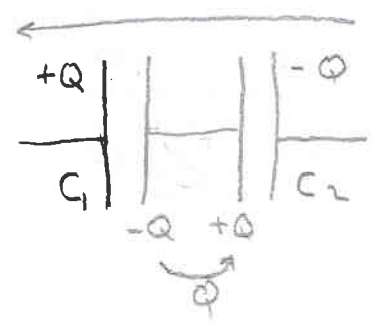
- Parallel



$$V = \frac{Q_1}{C_1} = \frac{Q_2}{C_2}$$

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- Series

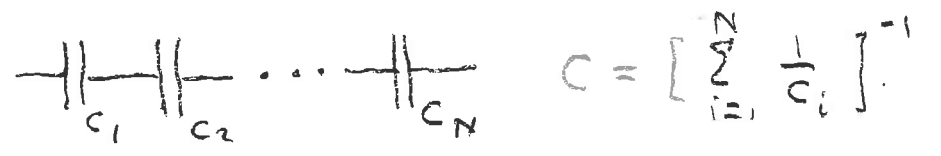


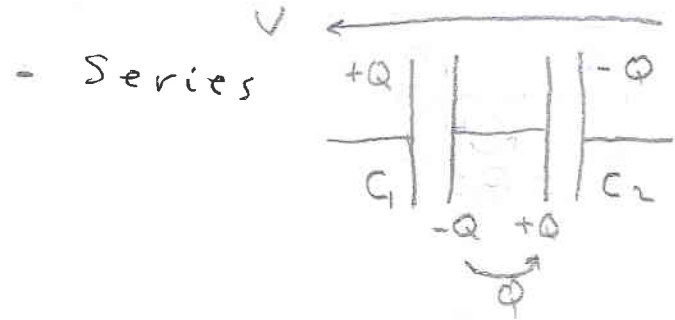
$$V = V_1 + V_2 = \frac{Q}{C_1} + \frac{Q}{C_2} = \frac{Q}{C}$$

$$\frac{1}{C_1} + \frac{1}{C_2} = \frac{1}{C}$$

$$\text{or } C = \frac{C_1 C_2}{C_1 + C_2}$$

- Easy to generalize to N





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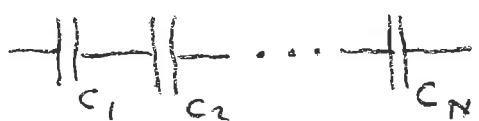
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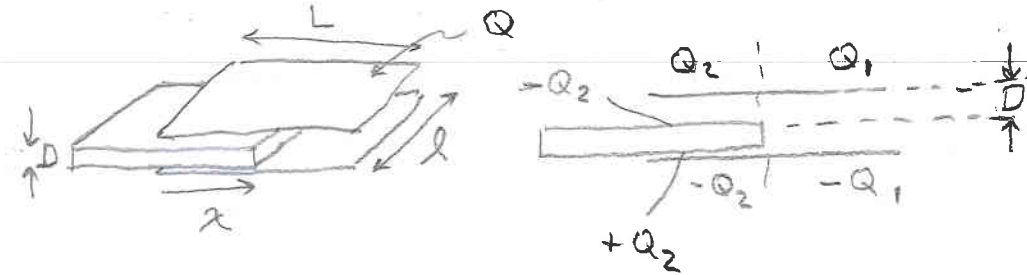


$$C = \sum_{i=1}^N C_i$$



$$C = \left[ \sum_{i=1}^N \frac{1}{C_i} \right]^{-1}$$

8 Problem: Find force on conducting slab pulled into parallel plate capacitor.



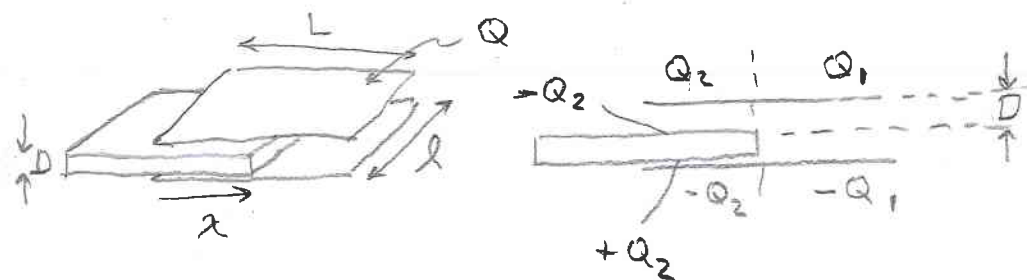
$$C(x) = \frac{1}{\frac{1}{C_1} + \frac{1}{C_2}} \quad C_1 = \frac{\ell x}{4\pi D}$$

$$C = C_1 + C_2 \quad C_2 = \frac{\ell(L-x)}{4\pi(2D)}$$

$$\begin{aligned} \text{Energy} &= \frac{Q^2}{2C} = \frac{1}{2} \frac{Q^2}{\frac{\ell x}{4\pi D} + \frac{\ell(L-x)}{4\pi(2D)}} \\ &= \frac{4\pi D Q^2 \ell}{x+L} \end{aligned}$$

$$\text{force} = - \frac{d}{dx} (\text{Energy}) = + \frac{4\pi D Q^2 \ell}{(x+L)^2}$$

8 Problem: Find force on conducting slab pulled into parallel plate capacitor. (23)



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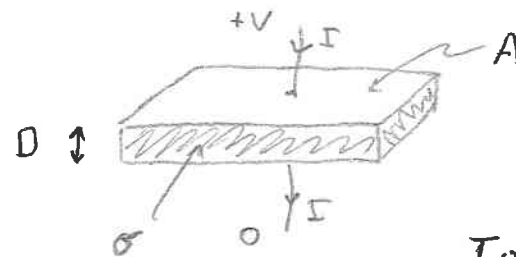
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G Ohm's law and circuit theorem (24)

1. Resistors Use  $\vec{j} = \sigma \vec{E}$

where  $\vec{E}$  is applied field and  $\vec{j}$  is the resulting flux or current of charge (esu/cm<sup>2</sup>)  
 $\sigma$  is conductivity of material

Look at an easy case:



$$E D = V$$

$$\vec{j} = \sigma \vec{E} = \sigma \frac{V}{D}$$

Total current

$$I = A \vec{j} = \frac{A \sigma}{D} V \equiv \frac{V}{R}$$

where the resistance

$$R = \frac{D}{A \sigma}$$

$$V = I R$$

Ohm's law

Expected behavior

Units  $esu = \frac{esu/cm}{esu/sec} = \frac{sec}{cm}$

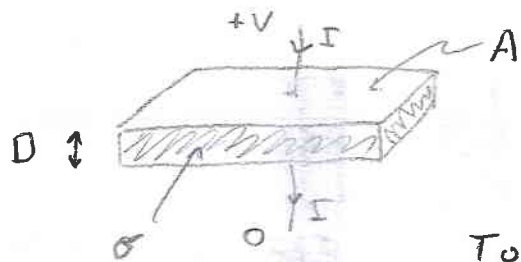
$$SI = \frac{\text{Volt}}{\text{Amp}} = \frac{\text{Volt}}{\text{Coul/sec}} \equiv \text{Ohm}$$

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$$SI = \frac{Volt}{Amp} = \frac{Volt}{coul/sec} \equiv Ohm$$

$$Ohm = \frac{Volt}{Coulomb/sec} = \frac{(1/300) statvolt sec}{3 \times 10^9 esu} \quad (25)$$

$$= \frac{1}{3 \times 10^{11}} \frac{sec}{cm}$$

Now the esu unit of  $\frac{sec}{cm}$  is impractically large, In general use



2. Circuit theory - introduce discrete elements with two terminals, Connect with high conductivity wires. So far we have



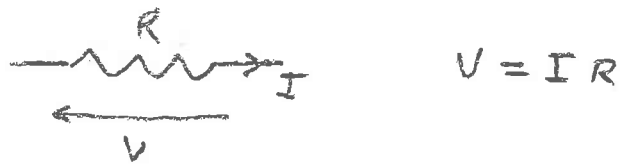
$$V_1 = I R_1, \quad V_2 = I R_2$$

$$V = V_1 + V_2 = I \underbrace{(R_1 + R_2)}_R$$

$$\text{Ohm} = \frac{\text{Volt}}{\text{Coulomb/sec}} = \frac{(1/300) \text{ stat volt sec}}{3 \times 10^9 \text{ esu}} \quad (25)$$

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$$V = IR$$

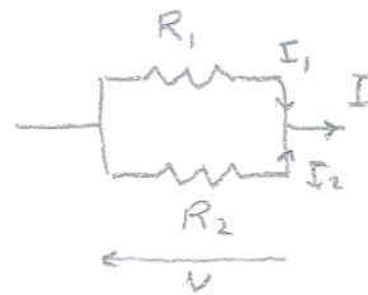
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$$V_1 = IR_1, \quad V_2 = IR_2$$

$$V = V_1 + V_2 = I \underbrace{(R_1 + R_2)}_R$$

parallel



$$I = I_1 + I_2$$

$$I = \frac{V}{R_1} + \frac{V}{R_2} = \left[ \frac{1}{R_1} + \frac{1}{R_2} \right] V = \frac{V}{R}$$

$$+ \frac{1}{R} = \frac{1}{R_1} + \frac{1}{R_2}$$